# CD4019BC Quad AND-OR Select Gate

#### FAIRCHILD

SEMICONDUCTOR TM

### CD4019BC Quad AND-OR Select Gate

#### **General Description**

The CD4019BC is a complementary MOS quad AND-OR select gate. Low power and high noise margin over a wide voltage range is possible through implementation of N- and P-channel enhancement mode transistors. These complementary MOS (CMOS) transistors provide the building blocks for the 4 "AND-OR select" gate configurations, each consisting of two 2-input AND gates driving a single 2-input OR gate. Selection is accomplished by control bits K<sub>A</sub> and K<sub>B</sub>. All inputs are protected against static discharge damage.

#### Features

- Wide supply voltage range: 3.0V to 15V
- High noise immunity: 0.45 V<sub>DD</sub> (typ.)
- Low power TTL compatibility: Fan out of 2 driving 74L or 1 driving 74LS

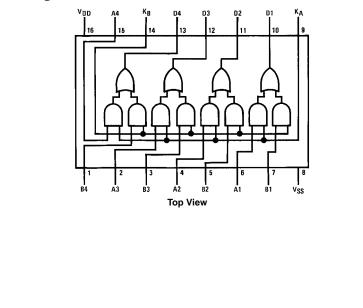
#### Applications

- AND-OR select gating
- Shift-right/shift-left registers
- True/complement selection
- AND/OR/EXCLUSIVE-OR selection

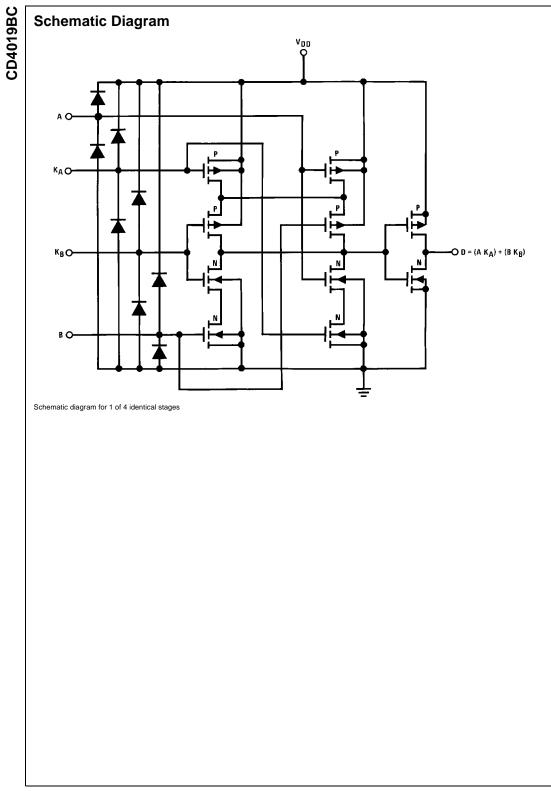
#### **Ordering Code:**

Order Number	Package Number	Package Description
CD4019BCM	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
CD4019BCN	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide
Devices also available i	in Tape and Reel. Specify b	by appending the suffix letter "X" to the ordering code.

#### **Connection Diagram**



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#### Absolute Maximum Ratings(Note 1)

(Note 2)		Conditions (Note 2)			
Supply Voltage (V <sub>DD</sub> )	-0.5V to +18V	DC Supply Voltage (V <sub>DD</sub> )	+3V to +15V		
Input Voltage (V <sub>IN</sub> )	–0.5V to V <sub>DD</sub> +0.5V	Input Voltage (V <sub>IN</sub> )	0V to V <sub>DD</sub> V		
Storage Temperature Range (T <sub>S</sub> )	$-65^{\circ}C$ to $+150^{\circ}C$	Operating Temperature Range (T <sub>A</sub> )	-55°C to +125°C		
Power Dissipation (P <sub>D</sub> )		Note 1: "Absolute Maximum Ratings" are those values beyond which the			
Dual-In-Line	700 mW	safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The tables of "Recom			
Small Outline	500 mW	W mended Operating Conditions" and "Electrical Characteristics" provide			
Lead Temperature (T <sub>L</sub> )		ditions for actual device operation. <b>Note 2:</b> $V_{SS} = 0V$ unless otherwise specified.			
(Soldering, 10 seconds)	260°C				

#### **Recommended Operation** Conditions (Note 2)

#### DC Electrical Characteristics (Note 3) –55°C +25°C +125°C Symbol Parameter Conditions Units Min Max Min Max Min Тур Max $V_{DD} = 5V$ I<sub>DD</sub> Quiescent Device 0.25 0.25 7.5 1 Current $V_{DD} = 10V$ 0.5 0.5 2 15 μΑ V<sub>DD</sub> = 15V 1.0 1.0 4 30 VOL LOW Level |I<sub>O</sub>| < 1 μA Output Voltage $V_{DD} = 5V$ 0.05 0.05 0.05 0 $V_{DD} = 10V$ 0.05 0 0.05 0.05 V $V_{DD} = 15V$ 0.05 0.05 0 0.05 HIGH Level |I<sub>O</sub>| < 1 μA V<sub>ОН</sub> Output Voltage $V_{DD} = 5V$ 4 95 4 95 5 4 95 $V_{DD} = 10V$ V 9.95 9.95 10 9.95 $V_{DD} = 15V$ 14.95 14.95 15 14.95 V<sub>IL</sub> LOW Level V<sub>DD</sub> = 5V, V<sub>O</sub> = 0.5V or 4.5V 1.5 2 1.5 1.5 Input Voltage $V_{DD} = 10V, V_O = 1.0V \text{ or } 9.0V$ 3.0 4 3.0 3.0 ٧ $V_{DD} = 15V, V_O = 1.5V \text{ or } 13.5V$ 4.0 6 4.0 4.0 $V_{DD} = 5V, V_{O} = 0.5V \text{ or } 4.5V$ VIH HIGH Level 3.5 3.5 3.5 3 $V_{DD} = 10V, V_{O} = 1.0V \text{ or } 9.0V$ Input Voltage 7.0 7.0 6 7.0 V V<sub>DD</sub> = 15V, V<sub>O</sub> = 1.5V or 13.5V 11.0 11.0 9 11.0 IOL LOW Level Output $V_{DD} = 5V, V_{O} = 0.4V$ 0.64 0.51 1 0.36 Current (Note 4) $V_{DD} = 10V, V_O = 0.5V$ 2.5 1.6 1.3 0.9 mΑ V<sub>DD</sub> = 15V, V<sub>O</sub> = 1.5V 4.2 3.4 10 2.4 HIGH Level Output $V_{DD} = 5V, V_{O} = 4.6V$ -0.25 -0.2 -0.4 -0.14 I<sub>OH</sub> Current (Note 4) V<sub>DD</sub> = 10V, V<sub>O</sub> = 9.5V -0.62 -0.5 -0.35 -1.0 mΑ $V_{DD} = 15V, V_O = 13.5V$ -1.8 -1.5 -3.0 -1.1 Input Current V<sub>DD</sub> = 15V, V<sub>IN</sub> = 0V -0.1 $-10^{-1}$ -0 10 $I_{\rm IN}$ -1.0 μΑ $V_{DD} = 15V, V_{IN} = 15V$ 10<sup>-5</sup> 0.1 0.10 1.0

Note 3: V<sub>SS</sub> = 0V unless otherwise specified

Note 4:  $\mathrm{I}_{\mathrm{OH}}$  and  $\mathrm{I}_{\mathrm{OL}}$  are tested one output at a time.

## CD4019BC

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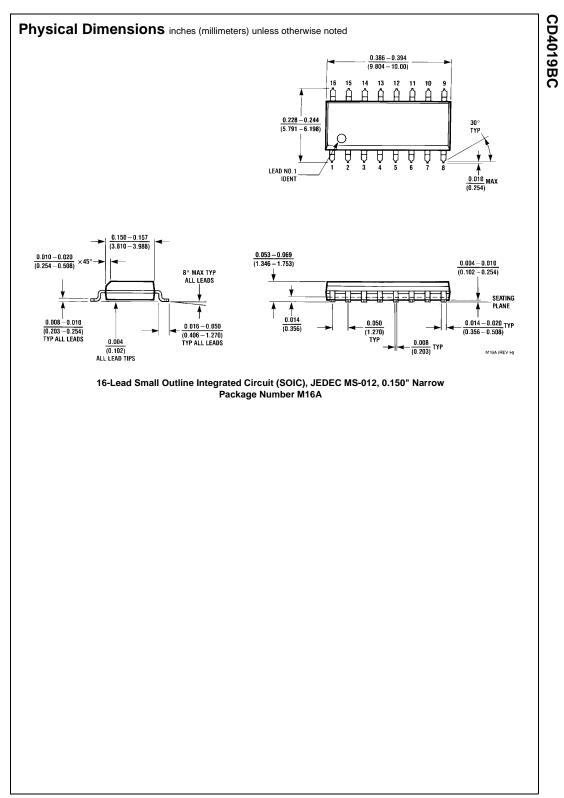
C
Ω
<u>_</u>
2
4
Ö
0

#### AC Electrical Characteristics (Note 5)

Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>PHL</sub> ,	Propagation Delay,	$V_{DD} = 5V$		100	300	
t <sub>PLH</sub> II	Input to Output	$V_{DD} = 10V$		50	120	ns
		$V_{DD} = 15V$		45	100	
INL	HIGH-to-LOW Level	$V_{DD} = 5V$		100	200	
	Transition Time	$V_{DD} = 10V$		50	100	ns
		$V_{DD} = 15V$		40	80	
t <sub>TLH</sub>	LOW-to-HIGH Level	$V_{DD} = 5V$		150	300	
	Transition Time	$V_{DD} = 10V$		70	140	ns
		$V_{DD} = 15V$		50	100	
C <sub>IN</sub>	Input Capacitance	All A and B Inputs		5	7.5	۶E
		K <sub>A</sub> and K <sub>B</sub> Inputs		10	15	pF

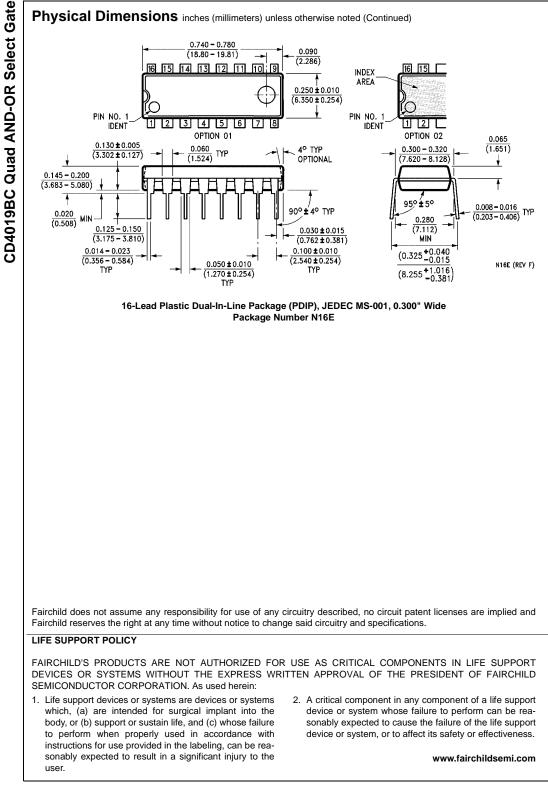
Note 5: AC Parameters are guaranteed by DC correlated testing.

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